

BIPOLAR ANALOG INTEGRATED CIRCUIT μ PC7900A Series

THREE TERMINAL NEGATIVE VOLTAGE REGULATOR

DESCRIPTION

 μ PC7900A series are monolithic three terminal negative regulators which employ internally current limiting, thermal shut down, output transistor safe operating area protection make them essentially indestructible.

They are intended as fixed voltage regulators in a wide range of application including local on card regulation for elimination of distribution problems associated wide single point regulation.

FEATURES

· Wide operation temperature range.

Ta: -30 °C to +85 °C

· Good load regulation.

7 mV TYP. (250 mA \leq Io \leq 750 mA): μ PC7905AHF

· Low noise.

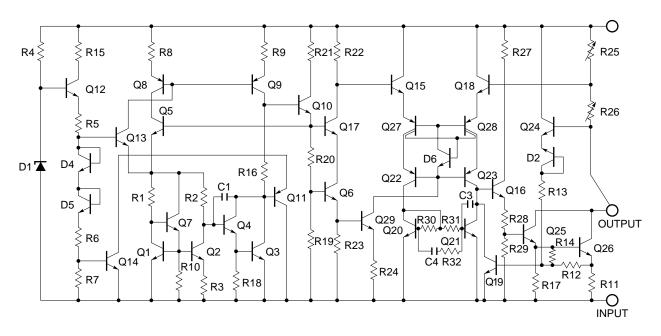
ORDERING INFORMATION

Part Number	Output Voltage	Package
μPC7905AHF	–5 V	MP-45G (ISOLATED TO-220)
μ PC7908AHF	-8 V	MP-45G (ISOLATED TO-220)
μ PC7912AHF	–12 V	MP-45G (ISOLATED TO-220)
μ PC7915AHF	−15 V	MP-45G (ISOLATED TO-220)
μ PC7918AHF	–18 V	MP-45G (ISOLATED TO-220)
μ PC7924AHF	–24 V	MP-45G (ISOLATED TO-220)

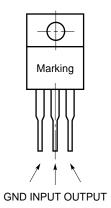
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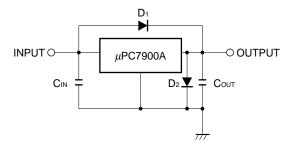
EQUIVALENT CIRCUIT



CONNECTION DIAGRAM



TYPICAL CONNECTION



Cin : More than 2.2 μ F Cout: More than 0.33 μ F D₁ : Needed for Vin > Vo D₂ : Needed for Vo > GND



ABSOLUTE MAXIMUM REATINGS (T_A = 25 °C)

Parameter	Symbol	Rating	Unit
Input Voltage	Vin	-35/-40 Note 1	V
Internal Power Dissipation	Рт	15 Note 2	W
Operating Ambient Temperature Range	Та	−30 to +85	°C
Operating Junction Temperature Range	TJ	-30 to +150	°C
Storage Temperature Range	T _{stg}	-55 to +150	°C
Thermal Resistance (junction to case)	Rth(J-C)	5.0	°C/W
Thermal Resistance (junction to ambient)	Rth(J-A)	65	°C/W

Note 1. μ PC7905A, 08A, 12A, 15A, 18A: -35 V, μ PC7924A: -40 V

2. Internally limited

RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Part Number	MIN.	TYP.	MAX.	Unit
Input Voltage	Vin	μPC7905AHF	-7	-10	-25	V
		μPC7908AHF	-10.5	-14	-25	
		μPC7912AHF	-14.5	-19	-30	
		μPC7915AHF	-17.5	-23	-30	
		μPC7918AHF	-21	-27	-33	
		μPC7924AHF	-27	-33	-38	
Output Current	lo	All	0.005		1	А
Operating Ambient Temperature	Та	All	-30		+85	°C
Operating Junction Temperature Range	Тл	All	-30		+125	°C



ELECTRICAL CHARACTERISTICS (T_A = 25 °C) μ PC7905A

(Vin = -10 V, I_0 = 500 mA, 0 °C \leq TJ \leq +125 °C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	Vo	T _J = 25 °C	-4.8	-5.0	-5.2	V
		$-7~V \leq V_{IN} \leq -20~V,~5~mA \leq I_{O} \leq 1~A,$ $P_{T} \leq 15~W$	-4.75		-5.25	
		–30 °C ≤ T _J ≤ +125 °C	-4.75		-5.25	
Line Regulation	REGIN	$T_J = 25$ °C, -7 V \leq VIN \leq -25 V		25	100	mV
		$T_J = 25$ °C, -8 V \leq V _{IN} ≤ -12 V		3	50	
Load Regulation	REG∟	$T_J = 25$ °C, 5 mA $\leq I_O \leq 1.5$ A		30	100	mV
		$T_J = 25$ °C, 250 mA $\leq I_0 \leq 750$ mA		7	50	
Quiescent Current	IBIAS	T _J = 25 °C		3.6	6.0	mA
Quiescent Current Change	ΔI BIAS	$-7 \text{ V} \leq \text{V}_{\text{IN}} \leq -25 \text{ V}$			1.3	mA
		5 mA ≤ lo ≤ 1 A			0.5	
Output Noize Voltage	Vn	$T_J = 25$ °C, 10 Hz $\leq f \leq$ 100 kHz		77		μVr.m.s
Ripple Rejection	R•R	$T_{J} = 25~^{\circ}C, f = 120~Hz, -8~V \leq V_{IN} \leq -18~V, \\ Io = 500~mA$	56	63		dB
Dropout Voltage	VDIF	T _J = 25 °C, Io = 1A		1.2		V
Peak Output Current	lOpeak	T _J = 25 °C	1.6	2.2	2.8	А
Temperature Coefficient of Output Voltage	ΔVο/ΔΤ	lo = 5 mA		0.36		mV/°C

μ PC7908A

(Vin = -14 V, lo = 500 mA, 0 $^{\circ}$ C \leq TJ \leq +125 $^{\circ}$ C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	Vo	T _J = 25 °C	-7.7	-8.0	-8.3	V
		$-10.5 \text{ V} \leq V_{\text{IN}} \leq -23 \text{ V}, \text{ 5 mA} \leq I_0 \leq 1 \text{ A},$ $P_T \leq 15 \text{ W}$	-7.6		-8.4	
		–30 °C ≤ T _J ≤ +125 °C	-7.6		-8.4	
Line Regulation	REGIN	$T_J = 25$ °C, -10.5 V \leq VIN \leq -25 V		33	150	mV
		$T_J = 25$ °C, -11 V \leq V _{IN} ≤ -17 V		14	75	
Load Regulation	REG∟	$T_J = 25$ °C, 5 mA $\leq I_0 \leq 1.5$ A		40	160	mV
		$T_J = 25$ °C, 250 mA $\leq I_0 \leq 750$ mA		14	80	
Quiescent Current	IBIAS	T _J = 25 °C		3.9	6.0	mA
Quiescent Current Change	ΔI BIAS	$-10.5 \text{ V} \le \text{V}_{IN} \le -25 \text{ V}$			1.0	mA
		5 mA ≤ lo ≤ 1 A			0.5	
Output Noize Voltage	Vn	$T_J = 25 ^{\circ}C$, 10 Hz $\leq f \leq$ 100 kHz		130		μVr.m.s
Ripple Rejection	R•R	$T_J = 25~^{\circ}C, -11.5~V \le V_{IN} \le -21.5~V,$ $f = 120~Hz, lo = 500~mA$	52	58		dB
Dropout Voltage	VDIF	T _J = 25 °C, I _O = 1 A		1.2		V
Peak Output Current	lOpeak	T _J = 25 °C	1.6	2.2	2.8	Α
Temperature Coefficient of Output Voltage	ΔVο/ΔΤ	lo = 5 mA		0.32		mV/°C



 $\mu PC7912A$ (Vin = -19 V, Io = 500 mA, 0 °C \leq TJ \leq +125 °C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	Vo	T _J = 25 °C	-11.5	-12	-12.5	V
		$-14.5 \text{ V} \leq \text{V}_{\text{IN}} \leq -27 \text{ V}, \text{ 5 mA} \leq \text{Io} \leq 1 \text{ A},$ $P_{\text{T}} \leq 15 \text{ W}$	-11.4		-12.6	
		–30 °C ≤ TJ ≤ +125 °C	-11.4		-12.6	
Line Regulation	REGIN	$T_J = 25$ °C, -14.5 V \leq V _{IN} \leq -30 V		60	200	mV
		$T_J = 25 ^{\circ}C, -16 V \leq V_{IN} \leq -22 V$		25	100	
Load Regulation	REG∟	$T_J = 25$ °C, 5 mA $\leq I_0 \leq 1.5$ A		70	220	mV
		T _J = 25 °C, 250 mA ≤ I _O ≤ 750 mA		20	110	
Quiescent Current	IBIAS	T _J = 25 °C		4.1	6.2	mA
Quiescent Current Change	ΔI BIAS	-14.5 V ≤ V _{IN} ≤ -30 V			1.0	mA
		5 mA ≤ lo ≤ 1A			0.5	
Output Noize Voltage	Vn	$T_J = 25 ^{\circ}\text{C}, 10 \text{Hz} \leq f \leq 100 \text{kHz}$		140		μVr.m.s
Ripple Rejection	R•R	$T_{J} = 25~^{\circ}C, \ f = 120~Hz, \ -15~V \leq V_{IN} \leq -25~V,$ $I_{O} = 500~mA$	49	56		dB
Dropout Voltage	VDIF	T _J = 25 °C, Io = 1A		1.2		V
Peak Output Current	lOpeak	T _J = 25 °C	1.6	2.2	2.8	Α
Temperature Coefficient of Output Voltage	ΔVο/ΔΤ	lo = 5 mA		0.04		mV/°C

μ PC7915A

(Vin = -23 V, lo = 500 mA, 0 $^{\circ}$ C \leq TJ \leq +125 $^{\circ}$ C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	Vo	T _J = 25 °C	-14.4	-15	-15.6	V
		$-17.5 \text{ V} \leq V_{\text{IN}} \leq -30 \text{ V}, \text{ 5 mA} \leq Io \leq 1 \text{ A},$ $P_T \leq 15 \text{ W}$	-14.25		-15.75	
		–30 °C ≤ T _J ≤ +125 °C	-14.25		-15.75	
Line Regulation	REGIN	$T_J = 25$ °C, -17.5 V \leq VIN \leq -30 V		60	200	mV
		$T_J = 25$ °C, -20 V $\leq V_{IN} \leq -26$ V		30	100	
Load Regulation	REG∟	$T_J = 25$ °C, 5 mA $\leq I_0 \leq 1.5$ A		100	300	mV
		$T_J = 25$ °C, 250 mA $\leq lo \leq 750$ mA		30	150	
Quiescent Current	IBIAS	T _J = 25 °C		4.2	6.2	mA
Quiescent Current Change	ΔI BIAS	$-17.5 \text{ V} \le \text{V}_{IN} \le -30 \text{ V}$			1.0	mA
		5 mA ≤ lo ≤ 1 A			0.5	
Output Noize Voltage	Vn	$T_J = 25$ °C, 10 Hz \leq f \leq 100 kHz		240		μVr.m.s
Ripple Rejection	R•R	$T_J = 25$ °C, f = 120 Hz, -18.5 V \leq V _{IN} \leq -28.5 V, lo = 500 mA	47	54		dB
Dropout Voltage	V _{DIF}	T _J = 25 °C, Io = 1 A		1.2		V
Peak Output Current	lOpeak	T _J = 25 °C	1.6	2.2	2.8	А
Temperature Coefficient of Output Voltage	ΔVο/ΔΤ	lo = 5 mA		1.2		mV/°C



 μ PC7918A

(Vin = -27 V, Io = 500 mA, 0 $^{\circ}$ C \leq TJ \leq +125 $^{\circ}$ C)

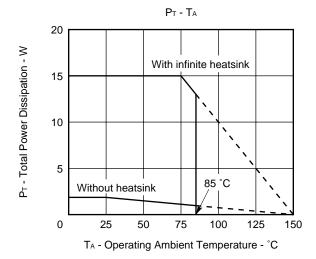
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	Vo	T _J = 25 °C	-17.3	-18	-18.7	V
		$-21~V \leq V_{IN} \leq -33~V,~5~mA \leq I_0 \leq 1~A,$ $P_T \leq 15~W$	-17.1		-18.9	
		$-30~^{\circ}\text{C} \le \text{T}_{\text{J}} \le +125~^{\circ}\text{C}$	-17.1		-18.9	
Line Regulation	REGIN	$T_J = 25$ °C, -21 V \leq VIN ≤ -33 V		60	240	mV
		$T_J = 25$ °C, -24 V \leq VIN ≤ -30 V		30	120	
Load Regulation	REG∟	$T_J = 25$ °C, 5 mA $\leq I_0 \leq 1.5$ A		125	360	mV
		$T_J = 25$ °C, 250 mA $\leq I_0 \leq 750$ mA		47	180	
Quiescent Current	IBIAS	T _J = 25 °C		4.1	6.5	mA
Quiescent Current Change	ΔI BIAS	$-21 \text{ V} \leq \text{V}_{IN} \leq -33 \text{ V}$			1.0	mA
		5 mA ≤ lo ≤ 1 A			0.5	
Output Noize Voltage	Vn	$T_J = 25$ °C, 10 Hz \leq f \leq 100 kHz		190		μVr.m.s
Ripple Rejection	R•R	$T_{J} = 25~^{\circ}C,~f = 120~Hz,~-22~V \leq V_{IN} \leq -32~V,$ $I_{O} = 500~mA$	45	53		dB
Dropout Voltage	VDIF	T _J = 25 °C, Io = 1 A		1.2		V
Peak Output Current	lOpeak	T _J = 25 °C	1.6	2.2	2.8	А
Temperature Coefficient of Output Voltage	ΔVο/ΔΤ	lo = 5 mA		0.24		mV/°C

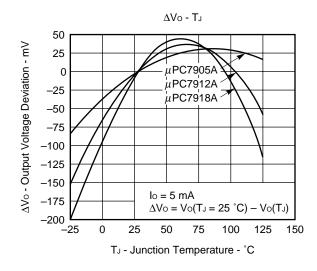
μ**PC7924A**

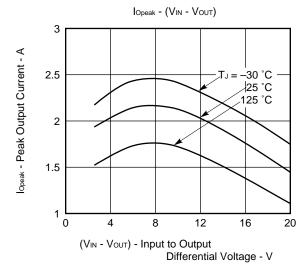
(Vin = -33 V, lo = 500 mA, 0 $^{\circ}$ C \leq TJ \leq +125 $^{\circ}$ C)

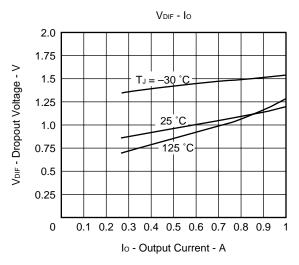
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	Vo	T _J = 25 °C	-23.0	-24	-25.0	V
		$-27~V \leq V_{IN} \leq -38~V,~5~mA \leq I_0 \leq 1~A,$ $P_T \leq 15~W$	-22.8		-25.2	
		$-30~^{\circ}\text{C} \le \text{T}_{\text{J}} \le +125~^{\circ}\text{C}$	-22.8		-25.2	
Line Regulation	REGIN	$T_J = 25$ °C, -27 V \leq V _{IN} ≤ -38 V		70	280	mV
		$T_J = 25$ °C, -30 V \leq VIN ≤ -36 V		37	140	
Load Regulation	REG∟	$T_J = 25$ °C, 5 mA $\leq I_0 \leq 1.5$ A		160	480	mV
		$T_J = 25$ °C, 250 mA $\leq I_0 \leq 750$ mA		60	240	
Quiescent Current	IBIAS	T _J = 25 °C		4.2	6.5	mA
Quiescent Current Change	ΔI BIAS	$-27 \text{ V} \leq \text{V}_{IN} \leq -38 \text{ V}$			1.0	mA
		5 mA ≤ lo ≤ 1 A			0.5	
Output Noize Voltage	Vn	$T_J = 25$ °C, 10 Hz \leq f \leq 100 kHz		240		μVr.m.s
Ripple Rejection	R•R	$T_{J} = 25~^{\circ}C,~f = 120~Hz,~-28~V \leq V_{IN} \leq -38~V,$ $I_{O} = 500~mA$	43	49		dB
Dropout Voltage	V _{DIF}	T _J = 25 °C, I _O = 1 A		1.2		V
Peak Output Current	lOpeak	T _J = 25 °C	1.6	2.2	2.8	А
Temperature Coefficient of Output Voltage	ΔVο/ΔΤ	lo = 5 mA		1.1		mV/°C

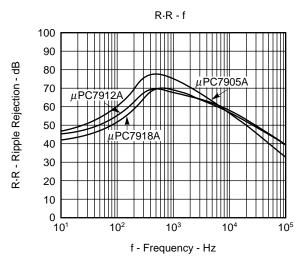
TYPICAL CHARACTERISTICS (TA = 25 °C)







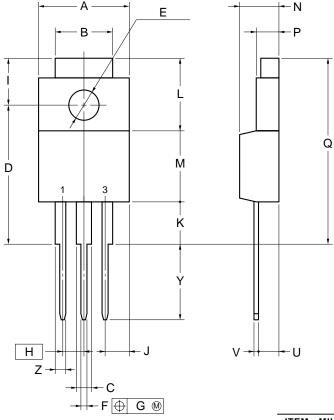






 μ PC7900AHF Series

3PIN PLASTIC SIP (MP-45G)



NOTE

Each lead centerline is located within 0.25 mm (0.01 inch) of its true position (T.P.) at maximum material condition.

MILLIMETERS	INCHES
10.4 MAX.	0.410 MAX.
7.0	0.276
1.2 MIN.	0.047 MIN.
17.0±0.3	$0.669^{+0.013}_{-0.012}$
φ3.3±0.2	φ0.130±0.008
0.75±0.10	$0.030^{+0.004}_{-0.005}$
0.25	0.010
2.54 (T.P.)	0.100 (T.P.)
5.0±0.3	0.197±0.012
2.66 MAX.	0.105 MAX.
4.8 MIN.	0.188 MIN.
8.5	0.335
8.5	0.335
4.5±0.2	0.177±0.008
2.8±0.2	$0.110^{+0.009}_{-0.008}$
22.4 MAX.	0.882 MAX.
2.4±0.5	$0.094^{+0.021}_{-0.020}$
0.65±0.10	0.026+0.004
8.9±0.7	0.350±0.028
1.0 MIN.	0.039 MIN.
	10.4 MAX. 7.0 1.2 MIN. 17.0±0.3 \$\psi 3.3±0.2 0.75±0.10 0.25 2.54 (T.P.) 5.0±0.3 2.66 MAX. 4.8 MIN. 8.5 8.5 4.5±0.2 2.8±0.2 22.4 MAX. 2.4±0.5 0.65±0.10 8.9±0.7

P3HF-254B-2



RECOMMENDED SOLDERING CONDITIONS

When soldering this product, it is highly recommended to observe the conditions as shown below. If other soldering processes are used, or if the soldering is performed under different conditions, please make sure to consult with our sales offices.

For more details, refer to our document "SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL" (C10535E).

TYPES OF THROUGH HOLE MOUNT DEVICE

μPC7900AHF Series

Soldering Process	Soldering Conditions	Symbol
Wave soldering	Solder temperature: 260 °C or below. Flow Time: 10 seconds or below.	

REFERENCE

Document Name	Document No.
NEC semiconductor device reliability/quality control system.	IEI-1212
Quality grade on NEC semiconductor devices.	C11531E
Semiconductor device mounting technology manual.	C10535E
IC package manual.	C10943X
Guide to quality assurance for semiconductor devices.	MEI-1202
Semiconductors selection guide.	X10679E

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NEC devices are classified into the following three quality grades:

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Standard: Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots

Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)

Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

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Anti-radioactive design is not implemented in this product.

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Datasheets for electronics components.